

66100**MICROCOUPLER, STANDARD TRANSISTOR OUTPUT****Mii****OPTOELECTRONIC PRODUCTS
DIVISION**

03/06/03

Features:

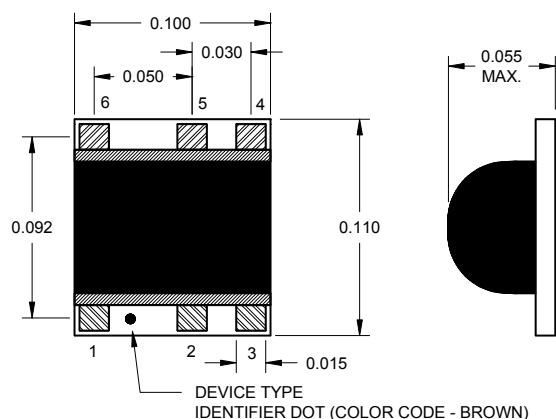
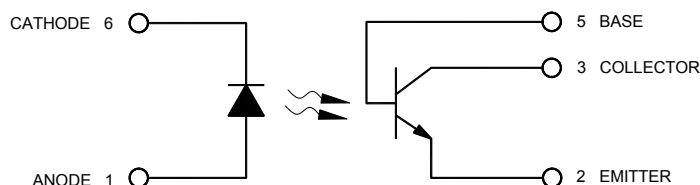
- CTR guaranteed from -55°C to $+125^{\circ}\text{C}$
- Small size saves real estate
- Large thick film gold bond pads
- Element evaluation on request
- Electrically similar to 4N2X and 4N4X couplers

Applications:

- Eliminate ground loops
- Level shifting
- Line receiver
- Solid state switching
- Switching power supplies

DESCRIPTION

The **66100** microcoupler is a single channel optocoupler consisting of an LED optically coupled to a light sensitive silicon phototransistor. Each microcoupler is provided with full 100% DC testing ($+100^{\circ}\text{C}$ test option upon request) or 100% element evaluation. All microcouplers are capable of operating over the full military temperature range (-55°C to $+125^{\circ}\text{C}$).

Package Dimensions**Schematic Diagram****ELECTRICAL CHARACTERISTICS** $T_a = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ unless otherwise specified.

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS	NOTE
Current Transfer Ratio	CTR1	100	200		%	$I_F = 10\text{mA}$, $V_{CE} = 5\text{V}$	1
	CTR2	100	200		%	$I_F = 1\text{mA}$, $V_{CE} = 5\text{V}$	
Input Diode Static Reverse Current	I_R			100	μA	$V_R = 3\text{V}$	
Input Diode Static Forward Voltage	V_F	0.9	1.3	1.7	V	$I_F = 10\text{mA}$	
Input-Output Insulation Leakage Current	I_{I-O}			1.0	μA	$V_{I-O} = 1500\text{VDC}$, R.H. < 50% $T_a = 25^{\circ}\text{C}$	2
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$			0.3	V	$I_F = 10\text{mA}$, $I_C = 2\text{mA}$, $I_B = 0$	
Collector-Base Breakdown Voltage	$V_{BR_{CBO}}$	70			V	$I_C = 10\mu\text{A}$, $I_B = 0$, $I_F = 0$	
					V	$T_a = 25^{\circ}\text{C}$	
Collector-Emitter Breakdown Voltage	$V_{BR_{CEO}}$	30			V	$I_C = 100\mu\text{A}$, $I_B = 0$, $I_F = 0$ $T_a = 25^{\circ}\text{C}$	
Emitter-Base Breakdown Voltage	$V_{BR_{EBO}}$	5			V	$I_C = 0$, $I_E = 100\mu\text{A}$, $I_F = 0$ $T_a = 25^{\circ}\text{C}$	
Off-State Collector Current	I_D			100	nA	$I_F = 0\text{mA}$, $V_{CE} = 20\text{V}$, $T_a = 25^{\circ}\text{C}$	
				100	μA	$I_F = 0\text{mA}$, $V_{CE} = 20\text{V}$, $T_a = 125^{\circ}\text{C}$	
Turn On Time	t_{ON}		5	15	μs	$I_F = 2\text{mA}$, $V_{CE} = 10\text{V}$, $R_L = 100\Omega$ $T_a = 25^{\circ}\text{C}$	
Turn Off Time	t_{OFF}		5	15	μs	$I_F = 2\text{mA}$, $V_{CE} = 10\text{V}$, $R_L = 100\Omega$ $T_a = 25^{\circ}\text{C}$	

NOTE:

1. Current Transfer Ratio is defined as the ratio of output collector current, I_O , to the forward LED input current, I_F , times 100%.
2. Measurement between pins 1 and 6 shorted together and pins 2, 3, 4, and 5 shorted together for duration of 1 second.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	MIN	MAX	UNITS
Input Current, Low Level	I_{FL}	0	100	μA
Input Current, High Level	I_{FH}	1	10	mA
Supply Voltage	V_{CE}	5	20	V
Operating Temperature	T_A	-55	125	$^{\circ}\text{C}$

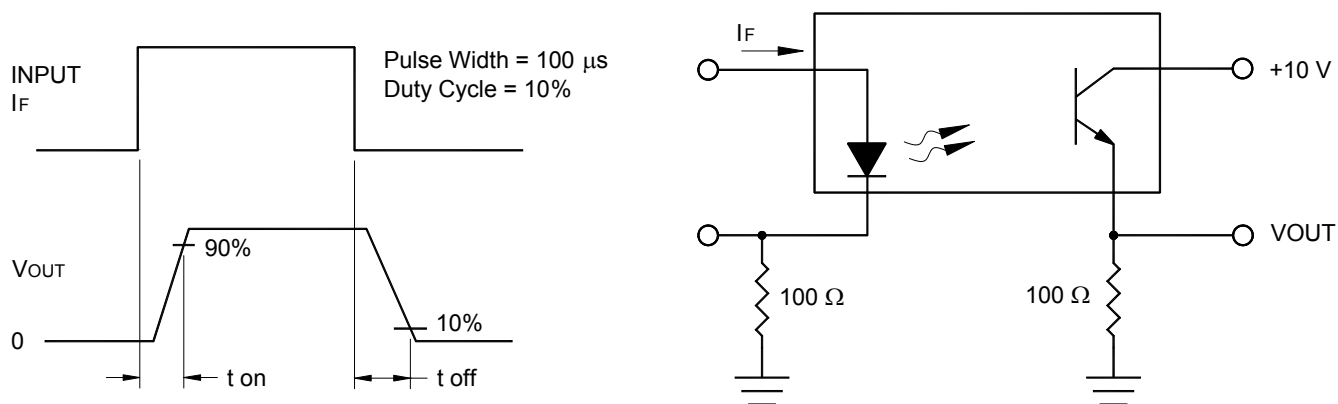


Figure 1. Switching Test Circuit